

View Online at <https://aerobasegroup.com/nsn/5961-00-905-7619>

**Inclosure Material:**

Metal all transistor

**Overall Length:**

0.860 inches all transistor

**Overall Diameter:**

1.220 inches all transistor

**Mounting Facility Quantity:**

1 all transistor

**Internal Configuration:**

Junction contact all transistor

**Joint Electronic Device Engineering Council/jedec/case Outline Designation:**

To-67 all transistor

**Internal Junction Configuration:**

Pnp all transistor

**Component Function Relationship:**

Matched

**Component Name And Quantity:**

4 transistor

**Mounting Method:**

Threaded stud all transistor

**Features Provided:**

Hermetically sealed case

**Thread Size:**

0.190 inches all transistor

**Semiconductor Material:**

Germanium all transistor

**Voltage Rating In Volts Per Characteristic:**

45.0 breakdown voltage, collector-to-emitter, base open all transistor

**Current Rating Per Characteristic:**

30.00 amperes source cutoff current all transistor

**Power Rating Per Characteristic:**

170.0 watts small-signal input power, common-collector absolute all transistor

**Transfer Ratio:**

45.0 static forward current transfer ratio, common-emitter all transistor and 160.0 static forward current transfer ratio, common-emitter all transistor

**Maximum Operating Temperature Per Measurement Point:**

125.0 degrees celsius junction all transistor

**Thread Series Designator:**

Unf all transistor

**Terminal Type And Quantity:**

2 tab, solder lug all transistor and 1 threaded stud all transistor

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

A110a0